

Liquid Crystal Analogue of Abrikosov Vortex Flow in Superconductors

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We extend the correspondence between the Renn-Lubensky Twist-Grain-Boundary-A phase in chiral liquid crystals and the Abrikosov mixed state in superconductors to dynamical aspects. We find that for a TGB sample with free boundaries, an external electric field applied along the helical axis induces a uniform translational motion of the grain boundary system - an analogue of the well-known mixed state flux flow. Likewise, an analogue of the mixed state Nernst effect is found. In much the same way in which the flux flow carries intercore electric fields generating Joule heat in an otherwise dissipation-free system, the grain boundary flow carries along polarized charges, resulting in a finite electric conductivity in a ferroelectric.

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The formal analogy of the smectic free energy within a Ginzburg-Landau approach, with that for the well known case of a superconductor has had a long history in the study of liquid crystals. It was first pointed out by de Gennes that the essential mean field features of the phase transition between the Nematic (N) and Smectic-A (SmA) phases can be derived by simply resorting to the correspondence with the Normal-Superconductor transition. [1] Corrections to this mean-field picture was studied by means of a large-N expansion of the GL energy functional, in which a runaway RG trajectory was interpreted as an indication of a fluctuation-driven first order transition. [2]

An important application of this analogy was carried out by Renn and Lubensky, who, based on the mean-field phase diagram of type-II superconductors in an applied magnetic field, predicted an intermediate phase lying between the cholesteric (Ch) and SmA phases. [3] This new phase, termed the Twist-Grain-Boundary-A (TGBA) phase, is the counterpart of the Abrikosov vortex lattice phase (also known as the mixed phase), and is composed of a regular network of screw dislocations. For the detailed structure of this lattice, readers are referred to ref. [3]. The TGBA phase was also independently discovered by experimenters [4], and immediately became a subject of intense research.

So far, theoretical investigations on the TGBA based on the superconductor analogy have been restricted to mean-field, static aspects. (See however refs [7-9].) Considering however the rich variety of mixed state physics that continues to be revealed [6] through recent (high Tc-motivated) studies of fluctuation effects and vortex dynamics, it is natural to ask what new feature arises when one seeks to extend the analogy in similar directions. As in high Tc superconductors, it is expected that thermal fluctuations have profound effects on the TGBA lattice structure; a simple estimate via the Ginzburg criteria strongly suggests this vulnerability, and there is an additional intrinsic instability towards disorder which is a

consequence of the very symmetry of the TGB. [7,5] However, a detailed study of the full effect of thermal fluctuation within the GL formalism requires considerable computing efforts, and we choose to set a less ambitious goal. In this paper, we study the fundamental properties of dislocation motion in the TGB system. As a result, we obtain several new entries to the list of superconductor-liquid crystal analogue, as summarized in Table 1. A major feature is the precise liquid crystal analogue of the flux flow motion of the Abrikosov vortex lattice. Although the long wavelength hydrodynamics of the TGBA phase has been previously worked out, [10] this paper is, to our knowledge, the first one which has considered the grain boundary itself and its constituent screw dislocation lines as mobile entities. An important implication of this motion is that the dislocation cores carry electric charges along with the flow through the ferroelectric media. Thus the system is predicted to be conductive.

To generate the motion of the dislocations, we will take advantage of the chiral nature of system. Due to the lack of chiral symmetry, polar vector fields can couple linearly to axial vector fields. If we consider the torque of the smectic layer normal as the latter and couple it to an external polar vector field, this will effectively exert a force on the grain boundary. As the external field, we consider (1) an electric field applied along the helical axis of TGBA phase and (2) temperature gradient imposed along the same direction.

In the SmA phase of such materials, it is well known that when an electric field is applied in-plane to the smectic layers, a finite tilting of the molecular axis from the smectic layer normal is favored. This phenomenon is called the electroclinic effect. [11] We shall show here that the stress induced by the electroclinic effect produces the driving force acting on screw dislocations. Our starting point is the following free energy, which is a combination of the covariant Chen-Lubensky (CL) model [3] and the energy related to the electroclinic effect. [11]:

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$$\begin{aligned}
F = & \int d^3x [r |\psi|^2 + C |(\nabla - iq_0 \mathbf{n})\psi|^2 + \frac{g}{2} |\psi|^4 \\
& + \frac{K_1}{2} (\nabla \cdot \mathbf{n})^2 + \frac{K_2}{2} (\mathbf{n} \cdot \nabla \times \mathbf{n} - k_0)^2 + \frac{K_3}{2} (\mathbf{n} \times \nabla \times \mathbf{n})^2 \\
& + \frac{\epsilon_0 E^2}{2} + \frac{P^2}{2\chi} - \eta (\mathbf{n}_0 \times (\nabla u - \delta \mathbf{n})) \cdot \mathbf{P}],
\end{aligned}
\tag{1}$$

where, \mathbf{n} is the Frank director, $\psi(\mathbf{x})$ is the smectic order parameter, $\psi(\mathbf{x}) = |\psi| e^{iq_0 u} e^{iq_0 \mathbf{n}_0 \cdot \mathbf{x}}$ with $q_0 = 2\pi/d$, d the separation between smectic layers, u the smectic layer displacement, \mathbf{n}_0 is the normal vector of smectic layer. η is the coupling constant between the polarization \mathbf{P} and $\mathbf{n}_0 \times (\nabla u - \delta \mathbf{n})$, and χ is the electric susceptibility. The terms $\eta (\mathbf{n}_0 \times (\nabla u - \delta \mathbf{n})) \cdot \mathbf{P}$ and $K_2 k_0 \mathbf{n} \cdot \nabla \times \mathbf{n}$ reflect the mentioned symmetry of the system. Differentiating F with respect to $\delta \mathbf{n}$, gives the stress field $\mathbf{J} \equiv -\frac{\delta F'}{\delta \delta \mathbf{n}} = B'(\mathbf{v} - \delta \mathbf{n})$ with $\mathbf{v} = \nabla u$, and $B' = 2Cq_0^2 |\psi|^2 - \eta^2 \chi$. J is analogous to the supercurrent \mathbf{J}_s which is the free energy differentiated with respect to the vector potential \mathbf{A} . x -axis, From the solutions of $\nabla \cdot \mathbf{J} = 0$ and $\frac{\delta F}{\delta \mathbf{n}} = 0$, we see that $\mathbf{v} - \delta \mathbf{n}_v - \delta \mathbf{n}_e$ is divided into two parts. One is the ‘‘vortex’’ part $\mathbf{v} - \delta \mathbf{n}_v$, [12] with nonvanishing curl, and the other is the uniform part, $\delta \mathbf{n}_e = \frac{\eta \chi (\mathbf{n}_0 \times \mathbf{E})}{B'}$, induced by the electric field \mathbf{E} . Applying the virtual work principle, we find a Peach-Koehler type force

$$\mathbf{f}_l = \mathbf{J}_e \times d\hat{\mathbf{z}}. \tag{2}$$

acting on each unit length of the dislocation. Here $d\hat{\mathbf{z}}$ is the Burgers vector.

Now we compare this with superconductors. $B'(\mathbf{v} - \delta \mathbf{n}_v)$ corresponds to the vortex part of the supercurrent, and $-B'\delta \mathbf{n}_e$ corresponds to the transport current. In the superconductor case, the corresponding force $\mathbf{f}_L = \mathbf{J}_t \times \Phi_0 \hat{\mathbf{z}}$ is just the Lorentz force acting on the vortex line per unit length. Φ_0 is the flux quantum. Comparing \mathbf{f}_l with \mathbf{f}_L , it is clear that the force acting on the single screw dislocation corresponds to Lorentz force in superconductors.

Next we consider the case where the Peach-Koehler force acts on the grain boundaries which is just an array of screw dislocations. For the grain boundary located at $x = 0$, the unit normals \mathbf{n}_0^L and \mathbf{n}_0^R of the SmA slab at $x < 0$ and $x > 0$, respectively are forced to be rotated with respect to each other around the x -axis by an angle of $2\pi\alpha$. A uniform electric field $\mathbf{E} = E\hat{\mathbf{x}}$ applied along the x -axis will generate the stress ‘‘currents’’ on the left and right ends of each SmA slab given by $\mathbf{J}_e^L = -\eta\chi\mathbf{n}_0^L \times \mathbf{E}$, and $\mathbf{J}_e^R = -\eta\chi\mathbf{n}_0^R \times \mathbf{E}$, respectively (See Fig1). The extension of eq.(2) to this configuration is straightforward and the force \mathbf{f}_{lgb} acting on the grain boundary per unit area is

$$\mathbf{f}_{lgb} = -\frac{\eta\chi Ed}{l_d} \cos(\pi\alpha)\hat{\mathbf{x}} \sim -2\eta\chi E\pi\alpha\hat{\mathbf{x}}, \tag{3}$$

where the final expression is valid for small α . This simple superposition is invalidated near $k = k_{c2}$ where dislocations cores begin to overlap.

Next we consider the case where a temperature gradient is imposed along the pitch. In analogy with the Nernst effect in a superconducting mixed phase, it is anticipated that screw dislocations in the TGBA phase are influenced by a thermal force generated in the direction of the temperature gradient. We shall show below that this is indeed the case. The physics of what is shown below may be summarized as follows. The temperature gradient produces the gradient of smectic density $|\psi|$, where $n_s = |\psi|^2$. This in turn disturbs the equilibrium of screw dislocations, giving rise to an effective driving force acting on the system.

Following the approach of Koklov and co-workers [13] who evaluated the Nernst coefficient for the superconductor case solely within the Ginzburg-Landau formalism, we can derive [5] an expression for the total force acting on the ensemble of screw dislocations in the case where the temperature gradient produces a steady nonequilibrium distribution of screw dislocations. For the condition (*i.e.* $\xi_s^2/l_b l_d \ll 1$ with ξ_s the smectic correlation length), the effective force per unit area on the grain boundary is

$$\begin{aligned}
\mathbf{f}_x = & \Lambda \frac{\nabla_x (\Delta n_s)}{n_s} \\
\sim & \frac{\nabla_x (\Delta n_s)}{n_s} \left(\frac{Bd^2}{2\pi l_d} \ln \left(\frac{l_d}{\xi_s} \right) + \frac{Bd^2 \lambda_2}{4l_d^2} \exp -\frac{l_d}{\lambda_2} \right).
\end{aligned}
\tag{4}$$

$B = 2Cq_0^2 |\psi|^2$, and the penetration length $\lambda_2 = \sqrt{K_2/B}$. It should be noted that the drift force \mathbf{f} is proportional to the gradient of smectic density $\nabla(\Delta n_s)$. The first term of the right hand side of eq. (4) has simple form of a single dislocation contribution multiplied by a factor of $1/l_d$, the density of screw dislocations in a layer. The second term reflects the global twisted structure of the TGBA system.

Now that we have obtained the forces induced by the coupling to external fields, we now turn to the actual motion of the dislocations.

We start with the ‘‘model A’’ type equation for the order parameter [14]:

$$\gamma_\psi \partial_t \psi = -\frac{\delta F}{\delta \psi_*} + \zeta(t). \tag{5}$$

$\zeta(t)$ is a thermal noise obeying the fluctuation-dissipation relation, $\langle \zeta(t)\zeta(t') \rangle = \frac{2k_B T}{|\gamma_\psi|} \delta(t-t')$. $\gamma_\psi = \gamma'_\psi + i\gamma''_\psi$ is generically a complex kinetic coefficient. Once the defect moves, we will have to consider the effect of a hydrodynamic lift force (Magnus force). The existence of such a force and its relevance to the Hall sign anomaly is an issue of present debate in superconductors. [15,16] It can be shown that a imaginary part of the relaxation time γ''_ψ in eq. (refptd) can give rise to such a force. However, renormalization-group calculation shows $(\gamma''_\psi/\gamma'_\psi)$ term to be an irrelevant perturbation in the vicinity of the transition point, *i. e.* near $k = k_{c2}$. [17] Furthermore, it was concluded in Ref. [18] that the force is absent in the single screw dislocation case. Thus we consider it

plausible to neglect such forces. and put $\gamma''_\psi/\gamma'_\psi = 0$. In this purely dissipative case, the motion of screw dislocation takes the form $\gamma_l \mathbf{v}_l = \mathbf{f}_l$, where γ_l is the viscosity coefficient for a screw dislocation and \mathbf{v}_l is its velocity. γ_l is determined using the Rayleigh functional for eq.(5) $R[\partial_t \psi, \partial_t \psi^*] = \int d^3x \gamma_\psi |\partial_t \psi|^2$, and the balance of force $\frac{\partial R}{\partial \mathbf{v}_l} = \mathbf{f}_l$. as $\gamma_l = \gamma_\psi \pi \ln(\lambda/\xi_s)$. [19] Hence the weak chirality regime, eq.(5) reduces to the stochastic equation for a single defect line, $\gamma_l \frac{d\mathbf{R}_l}{dt} = -\frac{\delta F}{\delta \mathbf{R}_l} + \mathbf{G}_l(t)$. The noise $\mathbf{G}_l(t)$ satisfies $\langle G_l(t)G_l(t') \rangle = \frac{2k_B T}{\gamma_l} \delta(t-t')$. Later we will show that the velocity $v_l = \frac{\eta \chi dE}{\gamma_l}$ is obtained from the experimental parameters η , χ , d .

At $k_0 \sim k_{c2}$ ($l_b l_d \sim \xi_s^2$) the screw dislocations cannot be treated as independent mobile entities. The static solutions of the linearized GL equation for ψ in the superconductor case near \mathbf{H}_{c2} can be approximated by eigenfunctions of the lowest Landau level. An analogous procedure can be taken for the TGBA case when $q_0/l_0 \gg 1$. [3] Here we add the time dependence into the solution.

$$\psi(\mathbf{x}) = \sum_s C_s \exp(i\mathbf{q}_\perp^s(x_s + U_s(t)) \cdot \mathbf{x}) \exp\left(-\frac{(k_0 x - k_0(x_s + U_s(t)))^2}{\xi^2}\right) \quad (6)$$

Here, x_s is the position of s -th SmA slab, $U_s(t)$ denotes the displacement of the zero of the s -th eigenfunction in the lowest Landau level. $\mathbf{q}_\perp^s(x_s + U_s(t)) = q_0(0, \sin(k_0(x_s + U_s(t))), \cos(k_0(x_s + U_s(t))))$, $\xi^2 = 1/(q_0 k_0)$. The dissipation function R per unit volume in this case $R = \frac{\gamma_\psi q_0 k_0 v_l^2 \sqrt{\pi}}{l_b q_0}$. As we will discuss next, the velocity v_l (now defined as the average velocities of the zeroes) is decided by combining R and the electric energy dissipation.

First we point out that a d.c. polarization current is directly observable as a direct consequence of the motion of screw dislocations. This is in sharp contrast to dislocation-free ferroelectrics, where only a.c. currents are allowed to flow. The origin of the charge carried by the screw dislocation stems from the chiral nature of the system. As can be seen from eq.(1), the deviation of the director vector from the layer normal gives rise to polarization. Around a screw dislocation this is obtained as $\mathbf{P} = -\frac{\eta d}{2\pi \lambda_2} \mathcal{K}_0\left(\frac{|\mathbf{x} - \mathbf{R}_l|}{\lambda_2}\right) \mathbf{e}_r + \chi \epsilon_0 \mathbf{E}$ per unit length, where \mathcal{K}_0 is the modified Bessel function, $\mathbf{e}_r = (\cos \phi, \sin \phi, 0)$, and $\phi = \tan^{-1}\left(\frac{y - \mathbf{R}_{ly}}{x - \mathbf{R}_{lx}}\right)$. Hence at the surface of the core of a screw dislocation we have a local charge accumulation of $Q = \int d\mathbf{S} \nabla \cdot \mathbf{P} = \eta \chi d$. Thus near k_{c1} we are able to relate the velocity to the polarization current by summing up the contribution $\partial_t Q$ and get

$$\mathbf{j}_p = \frac{\eta \chi d v_l \hat{\mathbf{x}}}{l_d b} = \eta \chi v_l \bar{k}_0 \hat{\mathbf{x}}_1. \quad (7)$$

Here, \bar{k}_0 is the spatially averaged twist of the director, for which the relation $\bar{k}_0 = \frac{d}{l_b l_d}$ for small α is used. Near k_{c2}

($\sqrt{l_d l_b} \sim \xi_s$) using the solution of eq. (6) leads to the same form as in eq. (7). As is the case of superconductors \bar{k}_0 is expressed in the form of the expansion of $\frac{k_{c2} - k_0}{k_0}$ near k_{c2} . The parameter $\bar{\beta}$ [3] (corresponding to Abrikosov's beta in superconductors) is related to the configuration of screw dislocation lattice. Differentiating the free energy with respect to $K_2 k_0$, we obtain $\bar{k}_0 = k_0 - \frac{k_{c2} - k_0}{2\kappa_2^2 \bar{\beta}}$ with $\kappa_2 = \frac{1}{C_{q_0}} \sqrt{\frac{g K_2}{2}}$. Demanding the dissipation due to the polarization current to coincide with R which is induced by the defects dynamics, we are able to express v_l as $v_l = \frac{\eta \chi d E l_b q_0 \bar{k}_0}{\gamma_\psi k_0 l_d \sqrt{\pi}}$ in terms of the material parameters k_0 , η , χ , and viscosity γ_ψ .

In summary we have investigated the basic electric properties of the dislocation motion in the TGBA phase, with a special emphasis on the analogy with vortex dynamics in superconductors. In actual experimental situations, rubbing process to fix the direction of directors of molecules should not be made in order to make the predicted effects observable. The present work should be considered a starting point for further studies of the dynamics in the TGB system, in which the interplay between thermal fluctuation and defect dynamics is expected to give rise to various interesting physics.

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FIG. 1. The stress field near the grain boundary. \mathbf{J}_v is the nonvanishing curl stress field around screw dislocations with its separation l_d . \mathbf{J}_e^L and \mathbf{J}_e^R is the electric field induced spatially uniform stress field of left SmA slab and right SmA slab, respectively.

FIG. 2. The smectic layers near the grain boundary. d is layer separation of SmA slabs. The angle between electric field induced stress field in left SmA slab \mathbf{J}_e^L along the Sm layer and that of right SmA slab \mathbf{J}_e^R is $2\pi\alpha$.

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| superconductors | liquid crystals |
| $\mathbf{j}_s = -\frac{\delta F}{\delta \mathbf{A}}$:supercurrent | $\mathbf{j} = -\frac{\delta F}{\delta \mathbf{n}}$:stress |
| Lorentz force | Peach-Koehler force |
| vortex lattice flow | grain boundary flow due to the electric field |
| Nernst effect | grain boundary flow due to the temperature gradient |
| flux flow resistivity | conductivity due to grain boundary flow |

TABLE I. Dynamical aspects of the analogy between superconductors and liquid crystals.